High Voltage Darlington Transistors

NPN Silicon

Features

• Pb–Free Packages are Available*

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
	3C372 3C373	V _{CEO}	100 80	Vdc
	3C372 3C373	V _{CES}	100 80	Vdc
Emitter-Base Voltage		V_{EBO}	12	Vdc
Collector Current – Continuous		۱ _C	1.0	Adc
Total Power Dissipation @ $T_A = 25^{\circ}C$ Derate above $T_A = 25^{\circ}C$		PD	625 5.0	mW mW/°C
Total Power Dissipation @ $T_A = 25^{\circ}$ Derate above $T_A = 25^{\circ}$ C	С	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range		T _J , T _{stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

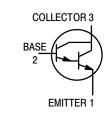
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	200	°C/W
Thermal Resistance, Junction-to-Case	R_{\thetaJC}	83.3	°C/W

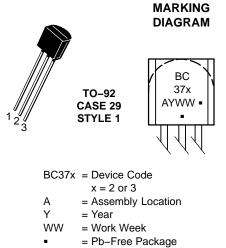
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
BC372	TO-92	5000 Units / Bulk
BC372G	TO–92 (Pb–Free)	5000 Units / Bulk
BC373	TO-92	5000 Units / Bulk
BC373G	TO–92 (Pb–Free)	5000 Units / Bulk
BC373RL1	TO-92	2000 / Tape & Reel
BC373RL1G	TO–92 (Pb–Free)	2000 / Tape & Reel
BC373ZL1	TO-92	2000 / Ammo Pack
BC373ZL1G	TO–92 (Pb–Free)	2000 / Ammo Pack

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

BC372, BC373

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage ⁽¹⁾ (I _C = 100 μ Adc, I _B = 0)	BC372 BC373	V _{(BR)CES}	100 80			Vdc
Collector – Base Breakdown Voltage $(I_C = 100 \ \mu Adc, I_E = 0)$	BC372 BC373	V _{(BR)CBO}	100 80			Vdc
Emitter – Base Breakdown Voltage ($I_E = 10 \ \mu Adc, I_C = 0$)		V _{(BR)EBO}	12	-	_	Vdc
Collector Cutoff Current $(V_{CB} = 80 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$	BC372 BC373	I _{CBO}			100 100	nAdc
Emitter Cutoff Current ($V_{EB} = 10 \text{ V}, I_C = 0$)		I _{EBO}	-	-	100	nAdc
ON CHARACTERISTICS (Note 1)						
DC Current Gain ($I_C = 250 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 100 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$)		h _{FE}	8.0 10		_ 160	К
Collector – Emitter Saturation Voltage ($I_C = 250 \text{ mAdc}$, $I_B = 0.25 \text{ mAdc}$)		V _{CE(sat)}	-	1.0	1.1	Vdc
Base – Emitter Saturation Voltage ($I_C = 250 \text{ mAdc}, I_B = 0.25 \text{ mAdc}$)		V _{BE(sat)}	-	1.4	2.0	Vdc
DYNAMIC CHARACTERISTICS				•		•
Current–Gain Bandwidth Product ($I_C = 100 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$)		f _T	100	200	_	MHz
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$		C _{ob}	-	10	25	pF
Noise Figure (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc, R _g = 100 k Ω , f = 1.0 kHz)		NF	-	2.0	-	dB

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle 2.0%.

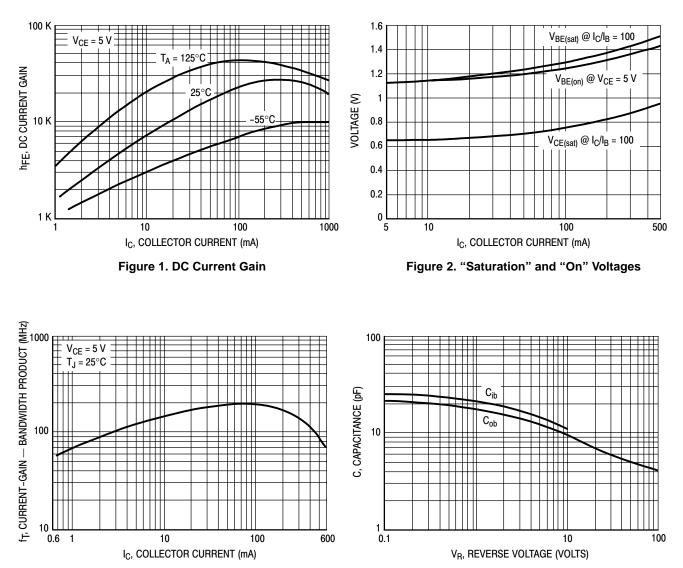
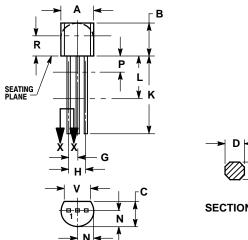


Figure 3. Current–Gain — Bandwidth Product

Figure 4. Capacitances

PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 **ISSUE AL**





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.

2.

CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 3.

LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
c	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Η	0.095	0.105	2.42	2.66	
ſ	0.015	0.020	0.39	0.50	
Κ	0.500		12.70		
Г	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.115		2.93		
×	0.135		3.43		

STYLE 1.

PIN 1. EMITTER

BASE
COLLECTOR

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